

HOME ABOUT I

INDUSTRIES

PRODUCTS & APPLICATIONS

NEWS & EVENTS

CONTACT & SUPPORT

EXTRANETS

Speed, Position & Current

Thermal

Pressure, Force & Flow

Relays

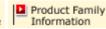
Switches & Equipment Health

Potentiometers & Resistors Safety Products Vehicle Controls & Monitoring Test & Measuremen

Honeywell Sensing and Control













Representative photograph, actual product appearance may vary.

- Dimensions
- Schematic
- Performance Charts
- Specifications

Click here for a print friendly version of this datasheet.

SDP8406-002

SDP Series Silicon PhotoTransistor, Side-looking Plastic Package

Features

Side-looking plastic package 50 ° (nominal) acceptance angle Wide sensitivity ranges Mechanically and spectrally matched to SEP8506 and SEP8706 infrared emitting diodes

Description

The SDP8406 is an NPN silicon phototransistor molded in a side-looking clear plastic package. The chip is positioned to accept radiation through a plastic lens from the side of the package.

Product Specifications	
Product Type	IR Component
Angular Response (Degree)	50
Light Current Minimum	1.80 mA
Light Current Maximum	3.60 mA
Package Style	Side-Looking
Package Components	Plastic
Package Color	Clear
Rise and Fall Time	15 μs
Power Dissipation	100 mW
Operating Temperature Range	-40 °C to 85 °C [-40 °F to 185 °F]
Dark Current	100 nA
Collector-Emitter Breakdown Voltage	30 V
Emitter-Collector Breakdown Voltage	5 V
Collector-Emitter Saturation Voltage	0.4 V
Comment	The radiation source is a tungsten lamp operating at a color temperature of 2870°K.
Availability	Global
Product Name	Phototransistor